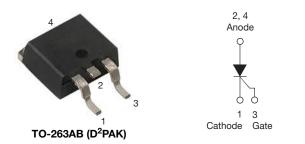
RoHS

COMPLIANT

HALOGEN

FREE

Thyristor High Voltage, Surface Mount Phase Control SCR, 16 A



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PRODUCT SUMMARY								
Package	TO-263AB (D ² PAK)							
Diode variation	Single SCR							
I _{T(AV)}	10 A							
V _{DRM} /V _{RRM}	800 V, 1200 V							
V _{TM}	1.4 V							
I _{GT}	60 mA							
TJ	-40 °C to +125 °C							

FEATURES

- J-STD-020, Meets MSL level 1, per LF maximum peak of 260 °C
- Designed and qualified according JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification (soft start)
- · Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-16TTS..SPbF high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	UNITS							
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 $\mu m)$ copper	2.5	3.5						
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	A					
Aluminum IMS with heatsink, $R_{thCA} = 5 \text{ °C/W}$	14.0	18.5						

Note

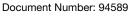
T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	10	Δ						
I _{RMS}		16	A						
V _{RRM} /V _{DRM}		800/1200	V						
I _{TSM}		200	A						
V _T	10 A, T _J = 25 °C	1.4	V						
dV/dt		500	V/µs						
dl/dt		150	A/µs						
TJ		-40 to +125	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} ∕I _{DRM} AT 125 °C mA						
VS-16TTS08SPbF	800	800	10						
VS-16TTS12SPbF	1200	1200	10						

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ABSOLUTE MAXIMUM RATINGS	i					
PARAMETER	SYMBOL		TEST CONDITIONS	VAL	UNITS	
FARAMETER	STINDUL		TEST CONDITIONS			UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 98 °C, ²	180° conduction, half sine wave	1	0	
Maximum RMS on-state current	I _{RMS}			1	6	А
Maximum peak, one-cycle,	1	10 ms sine p	pulse, rated V_{RRM} applied	17	70	~
non-repetitive surge current	I _{TSM}	10 ms sine p	ulse, no voltage reapplied	20	00	
Maximum I ² t for fusing	l ² t	10 ms sine p	ulse, rated V_{RRM} applied	144		A ² s
Maximum Pt for fusing	141	10 ms sine p	ulse, no voltage reapplied	200		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to	10 ms, no voltage reapplied	2000		A²√s
Maximum on-state voltage drop	V _{TM}	10 A, T _J = 25	5 °C	1.4		V
On-state slope resistance	r _t	T.I = 125 °C		24.0		mΩ
Threshold voltage	V _{T(TO)}	1J = 125 C		1.1		V
Maximum variance and divect lockage current	1 /1	T _J = 25 °C	V Deted V A/	0	.5	
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	1	0	
Holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C			150	mA
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25 \ ^{\circ}C$			00	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ max. linear to 80 % $V_{DRM} = R_g - k = Open$			00	V/µs
Maximum rate of rise of turned-on current	dl/dt			150		A/µs

TRIGGERING					
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	vv	
Maximum peak positive gate current	+ I _{GM}		1.5	А	
Maximum peak negative gate voltage	- V _{GM}		10	V	
	I _{GT}	Anode supply = 6 V, resistive load, T_J = - 10 °C	90		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$	60	mA	
		Anode supply = 6 V, resistive load, T_J = 125 °C	35		
		Anode supply = 6 V, resistive load, T_J = - 10 °C	3.0		
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$	2.0		
		Anode supply = 6 V, resistive load, T_J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}		0.25		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA	

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	$T_J = 25 \ ^{\circ}C$	0.9					
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs				
Typical turn-off time	tq	ij= izo 0	110					

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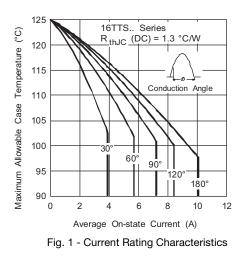


THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C				
Soldering temperature	T _S	For 10 s (1.6 mm from case)	260					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.3	°C/W				
Typical thermal resistance, junction to ambient	R _{thJA}	PCB mount ⁽¹⁾	40	0/10				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Marking davias				08S				
Marking device		Case style D ² PAK (SMD-220)	16TTS12S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W.

For recommended footprint and soldering techniques refer to application note #AN-994.



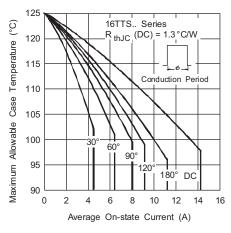


Fig. 2 - Current Rating Characteristics

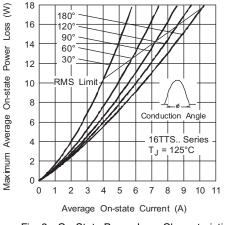


Fig. 3 - On-State Power Loss Characteristics

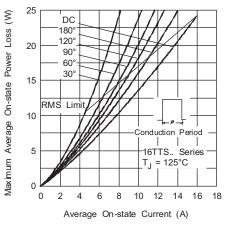


Fig. 4 - On-State Power Loss Characteristics

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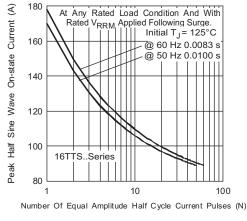
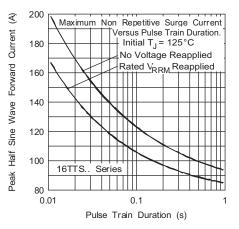
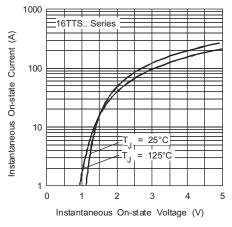
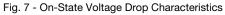


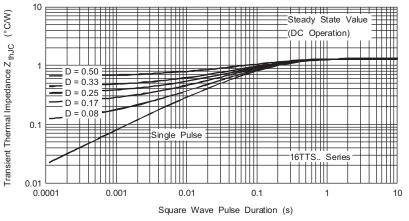
Fig. 5 - Maximum Non-Repetitive Surge Current









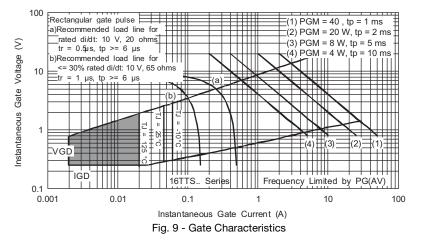




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VS-16TTS..SPbF Series

Vishay Semiconductors



ORDERING INFORMATION TABLE

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SHA

Device code	VS-	16	т	т	S	12	S	TRL	PbF
	1	2	3	4	5	6	7	8	9
	 Vishay Semiconductors product Current rating Circuit configuration: T = single thyristor Package: T = TO-220AC Type of silicon: 								
	6 - 7 - 8 -	- Vol - S = - • No • TF	S = standard recovery rectifier Voltage rating: Voltage code x 100 = V_{RRM} $08 = 800$ 12 = 1200 S = D ² PAK version • None = tube • TRL = tape and reel (left oriented) • TRR = tape and reel (right oriented)						
	9 -	- PbF	= lead	(Pb)-fre	e and R	oHS-co	ompliant	t	

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER T/R		MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-16TTS08SPbF	50	1000	Antistatic plastic tubes						
VS-16TTS08STRRPbF	800	800	13" diameter reel						
VS-16TTS08STRLPbF	800	800	13" diameter reel						
VS-16TTS12SPbF	50	1000	Antistatic plastic tubes						
VS-16TTS12STRRPbF	800	800	13" diameter reel						
VS-16TTS12STRLPbF	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

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Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3 0.25 BSC 0.010 BSC					
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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